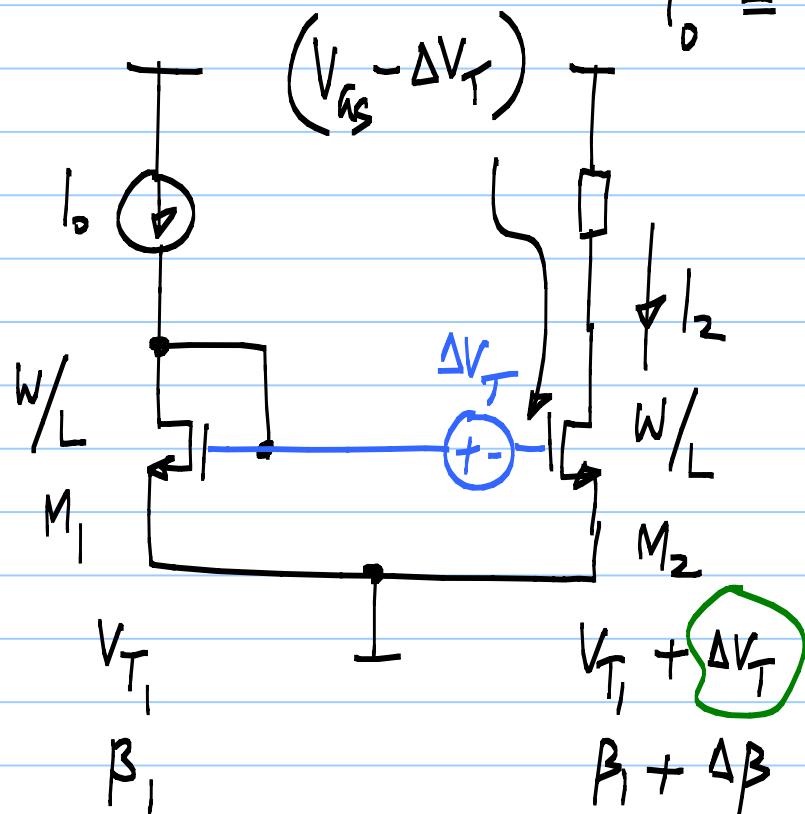


Lecture 23

$$I_2 = \left(\frac{\beta_1 + \Delta\beta}{2} \right) \left(V_{GS} - (V_T + \Delta V_T) \right)^2$$

$$I_0 = \frac{\beta_1}{2} \left(V_{GS} - V_T \right)^2$$



* Expand this expression

* neglect higher order

terms : ΔV_T^2 , $\Delta V_T \cdot \Delta\beta$

$$\Delta I_D = \frac{\partial I_D}{\partial V_{GS}} \cdot \Delta V_{GS} = g_m \cdot \Delta V_{GS}$$

$$I_2 = \left(\frac{\beta_1 + \Delta\beta}{2} \right) \left(V_{GS} - (V_T + \Delta V_T) \right)^2 \rightarrow \left(\frac{\beta_1 + \Delta\beta}{2} \right) \cdot (V_{GS} - V_T)^2$$

$$I_0 = \frac{\beta_1}{2} \left(V_{GS} - V_T \right)^2 \quad \xrightarrow{\Delta\beta} \frac{\beta_1}{2} \cdot (V_{GS} - \Delta V_T - V_T)^2$$

$\Delta\beta:$ $I_2 = \frac{\beta_1 + \Delta\beta}{\beta_1} \cdot I_0 = \left(1 + \frac{\Delta\beta}{\beta_1} \right) I_0$

$\Delta V_T:$ $I_2 = I_0 - g_m \cdot \Delta V_T$

$\Delta\beta, \Delta V_T:$ $I_2 = I_0 - g_m \Delta V_T + \frac{\Delta\beta}{\beta_1} \cdot I_0$

$$I_2 = I_0 - g_m \frac{\Delta V_T}{V_{AS} - V_T} + \frac{\Delta \beta}{\beta_1} \cdot I_0$$

$$g_m = \frac{2 I_0}{V_{AS} - V_T}$$

$$\frac{\Delta I}{I_0} = \frac{I_2 - I_0}{I_0} = - \frac{g_m \Delta V_T}{I_0} + \frac{\Delta \beta}{\beta_1} \cdot \frac{I_0}{I_0}$$

$$\left(\frac{\Delta I}{I_0} \right) = - \frac{g_m}{I_0} \cdot \frac{\Delta V_T}{V_{AS} - V_T} + \frac{\Delta \beta}{\beta_1}$$

$$= - \frac{2 \cdot \Delta V_T}{V_{AS} - V_T} + \frac{\Delta \beta}{\beta_1}$$

$$\sigma^2 \left(\frac{\Delta I}{I_0} \right) = \frac{4 \cdot \sigma^2_{V_T}}{(V_{AS} - V_T)^2} + \frac{\sigma^2_{\beta}}{\beta_1}$$

Mismatch in a current mirror:

$$\sigma \left\{ \left(\frac{\Delta I}{I_b} \right)^2 \right\} = \frac{4 \sigma_{V_T}^2}{(V_{AS} - V_T)^2} + \sigma_{\beta}^2$$
$$= \frac{4 A_{V_T}^2}{(V_{AS} - V_T)^2 \cdot WL} + \frac{A_{\beta}^2}{WL}$$

* Mismatch reduces with increasing WL

* Effect of V_T mismatch reduces with increasing $(V_{AS} - V_T)$

For a given current: $I_o = \frac{\beta}{2} \cdot (V_{AS} - V_T)^2$

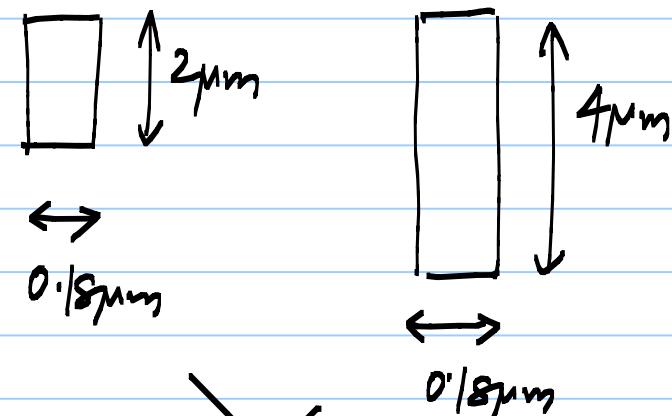
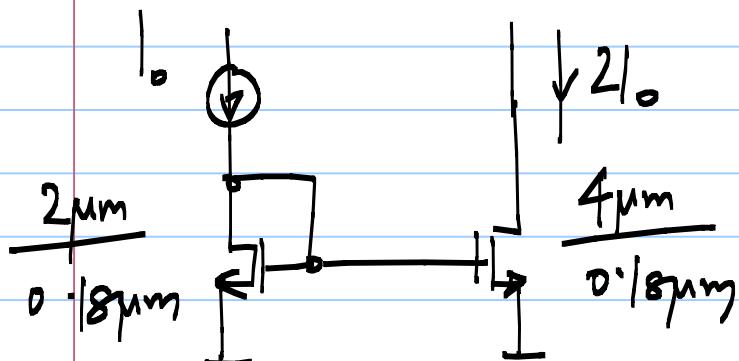
$$(V_{AS} - V_T)^2 = \frac{2I_o}{\beta} = \frac{2I_o}{MC_{ox} \frac{W}{L}}$$

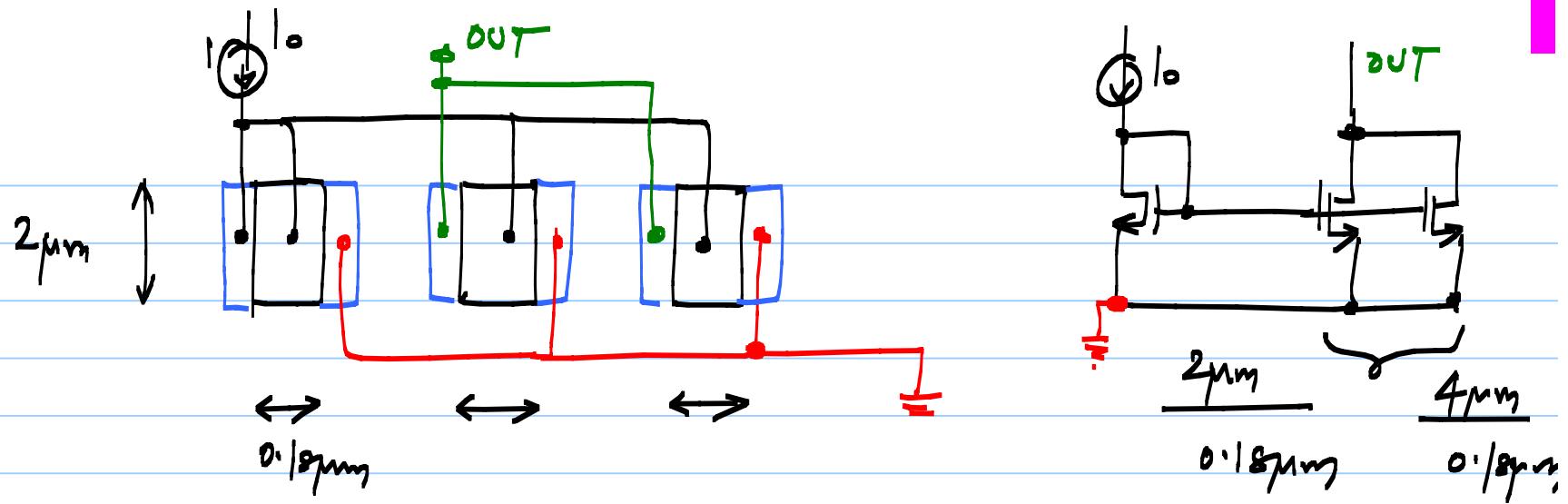
$$\sigma^2 \left(\frac{\Delta I}{I_o} \right) = \frac{4 \cdot A_{V_T}^2}{2I_o \frac{MC_{ox} \frac{W}{L}}{L}} + \frac{A_B^2}{WL}$$

$$= \frac{2MC_{ox}}{I_o} \cdot \frac{A_{V_T}^2}{L^2} + \frac{A_B^2}{WL}$$

Layout of MOS transistors:

- * Two transistors to be matched: Identical L
- * For good matching: Multiples of identical units

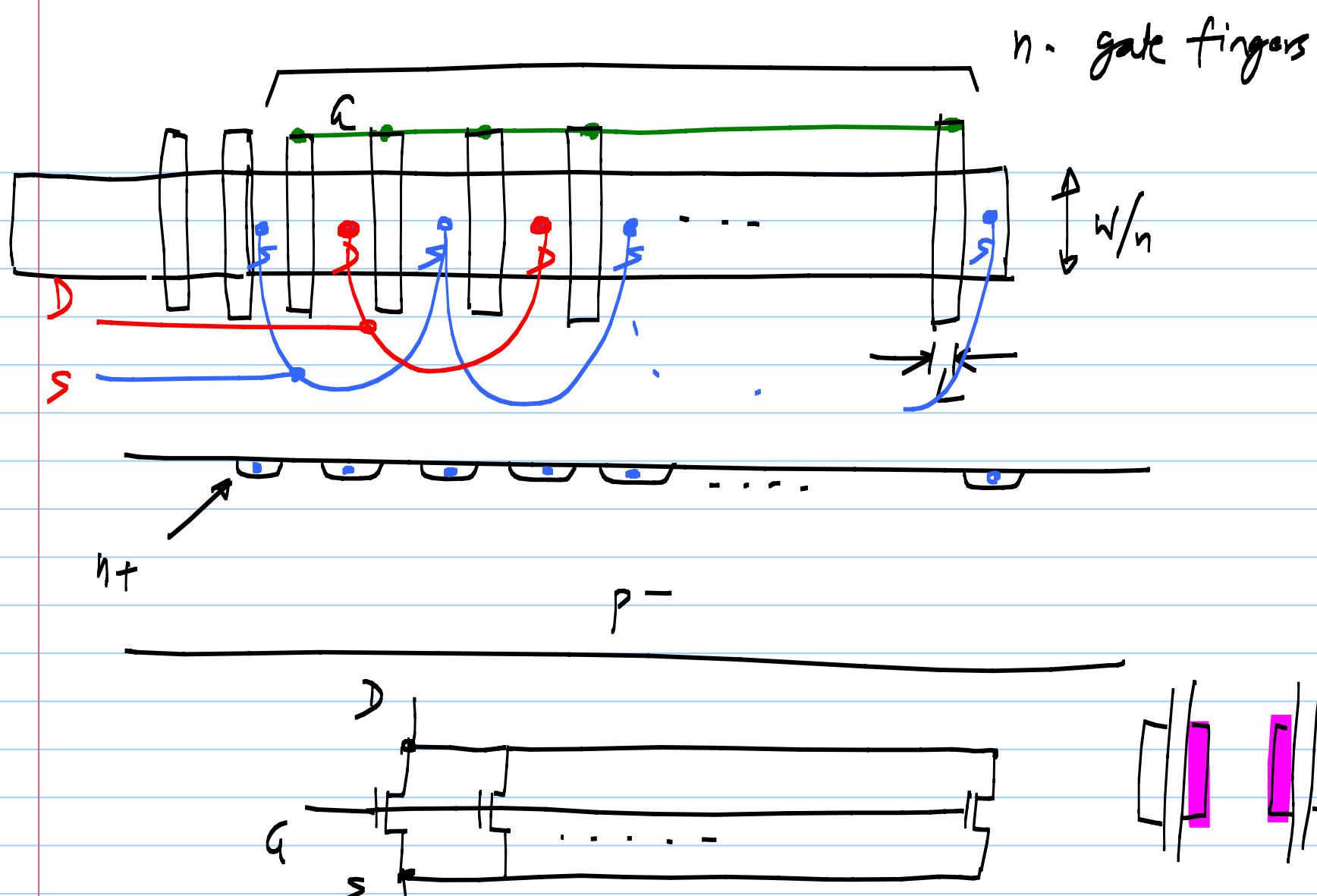


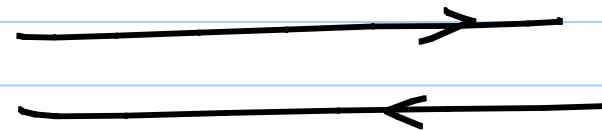
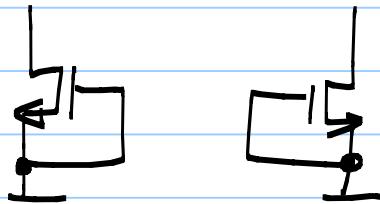
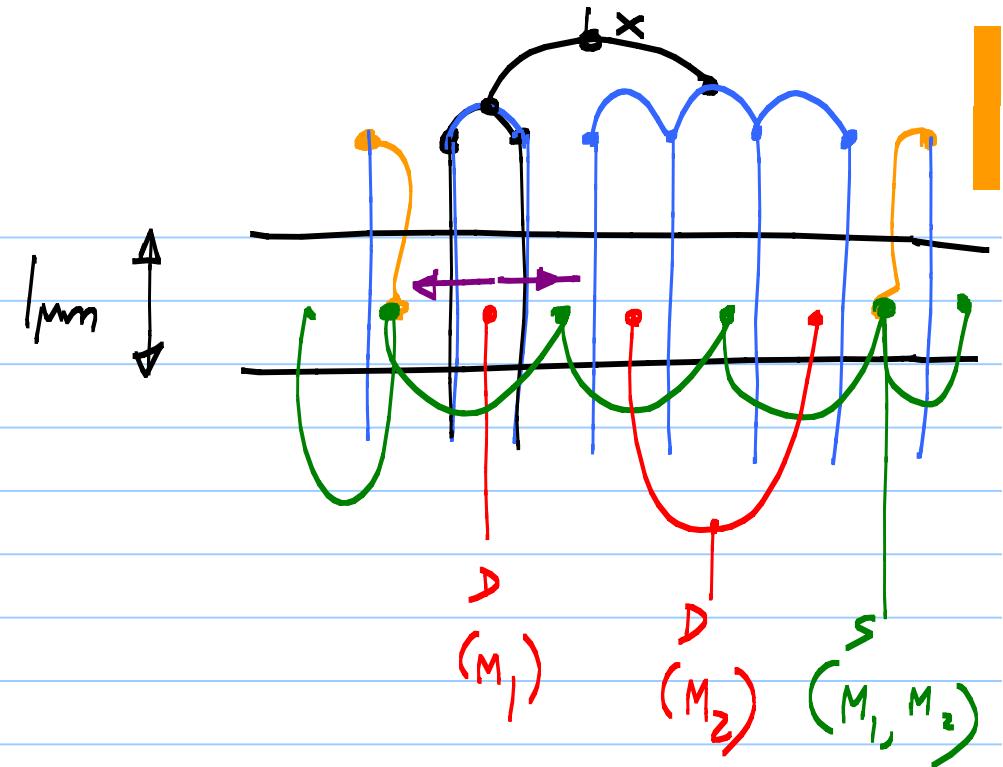
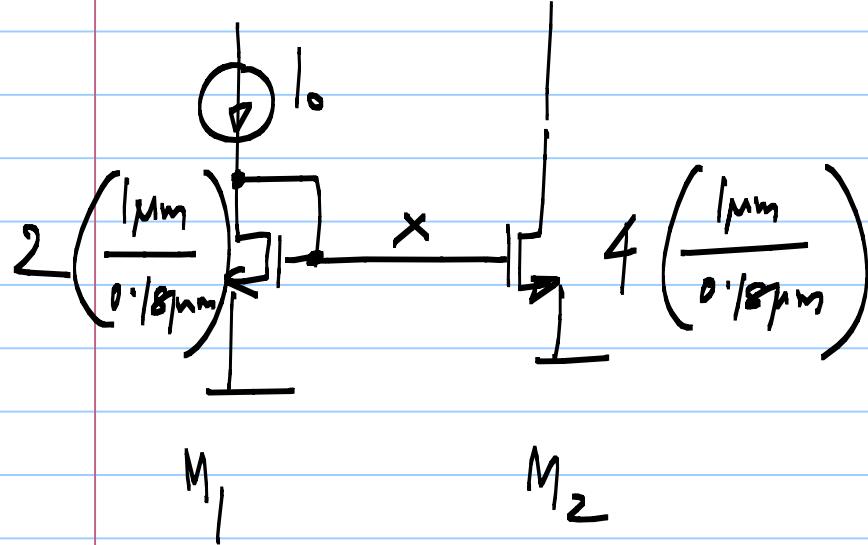


$$\frac{W}{L} = n \cdot \left(\frac{W/n}{L} \right)$$

n devices of $(\frac{W}{n}/L)$ in parallel

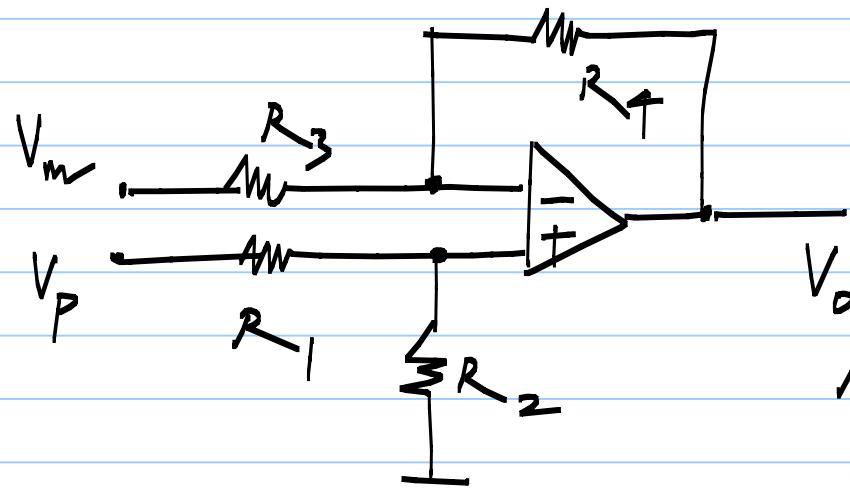
$\frac{W}{n} \sim 0.5 \mu\text{m}$ to a few μm





Even number of gate fingers

Differential to single ended converter:



$$V_d = (V_p - V_m)$$

V_d : when the 4 resistors
are different from
each other .

$$R_1 = R + \Delta R_1$$

$$R_2 = R + \Delta R_2$$

:

$$\begin{aligned}
 V_o &= V_p \left(\frac{R_2}{R_1 + R_2} \right) \left(1 + \frac{R_4}{R_3} \right) - V_m \cdot \frac{R_4}{R_3} \\
 &= V_p \cdot \frac{1 + \frac{R_4}{R_3}}{1 + \frac{R_1}{R_2}} - V_m \cdot \frac{R_4}{R_3}
 \end{aligned}$$

$$\frac{R_4}{R_3} = \frac{R + \Delta R_4}{R + \Delta R_3} = 1 + \frac{\Delta R_4 - \Delta R_3}{R}$$

$$\frac{R_1}{R_2} = 1 + \frac{\Delta R_1 - \Delta R_2}{R}$$

$$\begin{aligned}
 V_o &= V_p \cdot \frac{2 \left(1 + \frac{\Delta R_4 - \Delta R_3}{2R} \right)}{2 \left(1 + \frac{\Delta R_1 - \Delta R_2}{2R} \right)} - V_m \left(1 + \frac{\Delta R_4 - \Delta R_3}{R} \right) \\
 &= V_p \left\{ 1 + \frac{\Delta R_4 - \Delta R_3 + \Delta R_1 - \Delta R_2}{2R} \right\} - V_m \left\{ 1 + \frac{\Delta R_4 - \Delta R_3}{R} \right\}
 \end{aligned}$$